

Description

The AU0781D1F is an bi-directional TVS diode, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive data and power lines. The AU0781D1F complies with the IEC 61000-4-2 (ESD) with ± 30kV air and ± 30kV contact discharge. It is assembled into a SOD-123FL lead-free package. The small size and high ESD/surge protection make AU0781D1F an ideal choice to protect cell phone, digital cameras, audio players and many other portable applications.

Features

- Protects one data or power line
- Ultra low leakage: nA level
- Operating voltage: 7V
- Ultra low clamping voltage
- Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
 Air discharge: ±30kV
 - Contact discharge: ±30kV
 - IEC61000-4-5 (Lightning) 200A (8/20µs)
- RoHS Compliant

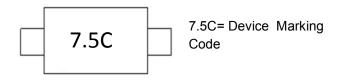
Mechanical Characteristics

- Package: SOD-123FL
- Lead Finish: Matte Tin
- Case Material: "Green" Molding Compound.
- Moisture Sensitivity: Level 3 per J-STD-020
- Terminal Connections: See Diagram Below
- Marking Information: See Below

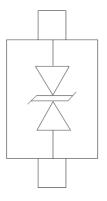
Applications

- Fast-charge battery chargers
- Power management system
- Cellular Handsets and Accessories
- Personal Digital Assistants
- Notebooks and Handhelds
- Portable Instrumentation
- Digital Cameras
- Peripherals

Marking Information



Pin Configuration



Circuit and Pin Schematic

Ordering Information

Part Number	Packaging	Reel Size	
AU0781D1F	3000/Tape & Reel	7 inch	



Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

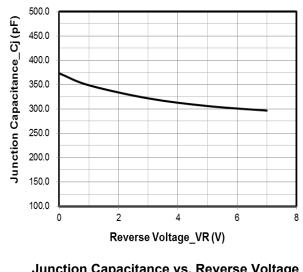
Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20µs)	Ppk	5000	W
Peak Pulse Current (8/20µs)	Ipp	200	А
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	Vesd	±30 ±30	kV
Operating Temperature Range	TJ	−55 to +125	°C
Storage Temperature Range	Tstg	−55 to +150	°C

Electrical Characteristics (T_A=25°C unless otherwise specified)

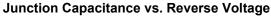
Parameter	Symbol	Min	Тур	Max	Unit	Test Condition
Reverse Working Voltage	VRWM			7	V	
Breakdown Voltage	VBR	7.5			V	IT = 1mA
Reverse Leakage Current	I _R			5	μA	VRWM = 7V
Clamping Voltage	Vc			9	V	IPP = 5A (8 x 20µs pulse)
Clamping Voltage	Vc		20	25	V	IPP = 200A (8 x 20µs pulse)
Junction Capacitance	Сл		400		pF	VR = 0V, f = 1MHz

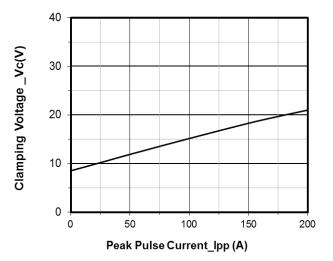


AU0781D1F

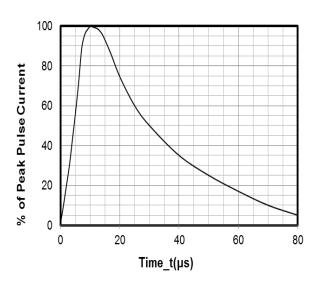


Typical Performance Characteristics (T_A=25°C unless otherwise Specified)

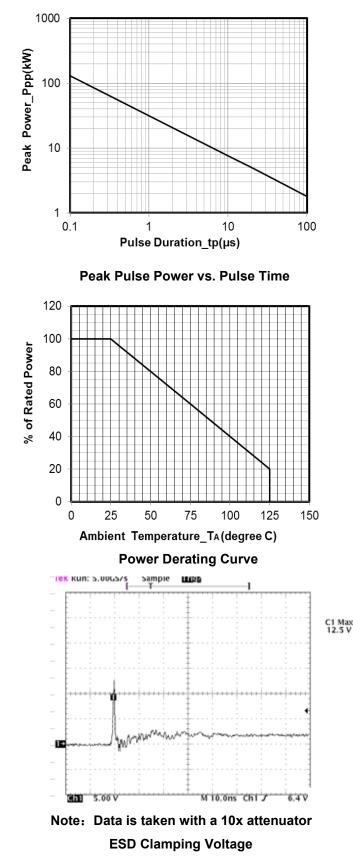




Clamping Voltage vs. Peak Pulse Current



8 X 20µs Pulse Waveform

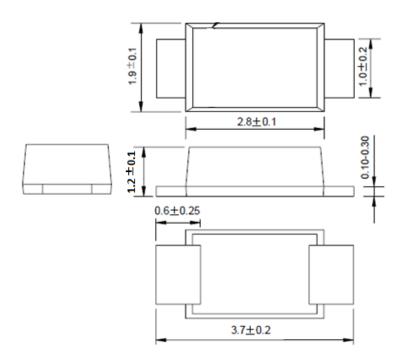


8 kV Contact per IEC61000-4-2



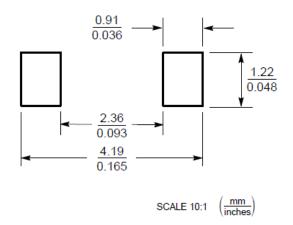
AU0781D1F

SOD-123FL Package Outline Drawing



Dimensions in millimeters

Suggested Land Pattern



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